



# THE DATASHEET OF FS7M0880TU

# FS7M0880

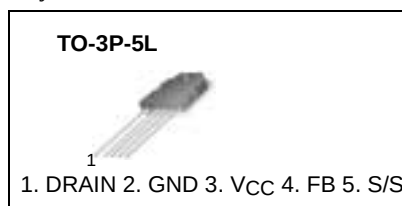
## Fairchild Power Switch(FPS)

### Features

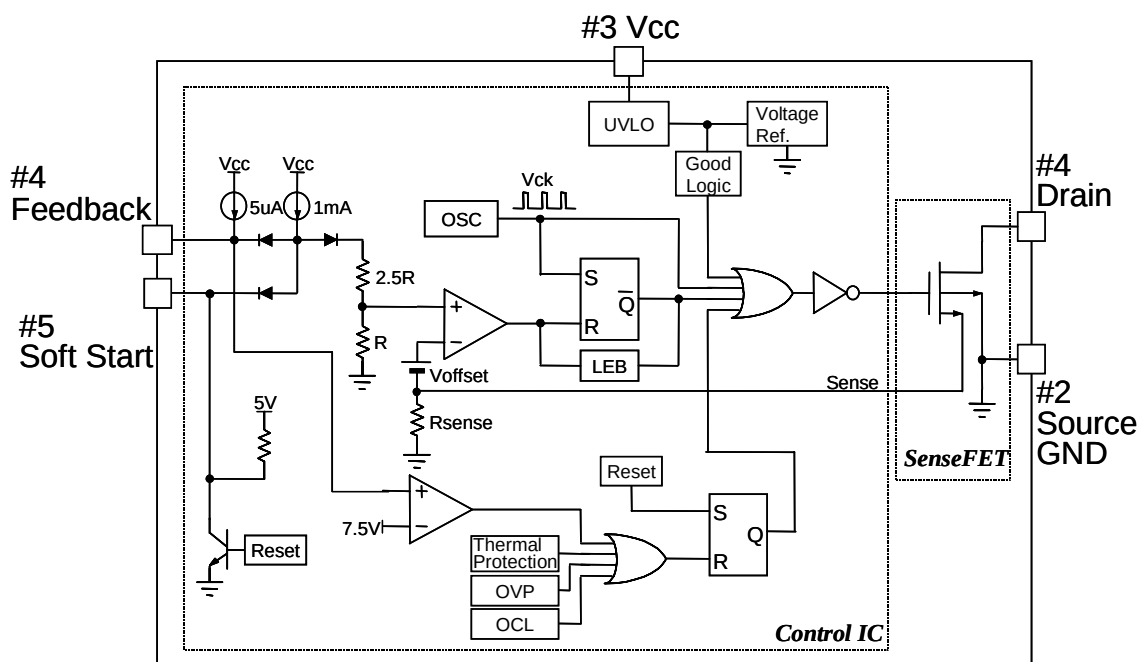
- Precision Fixed Operating Frequency
- FS7M0880(66kHz)
- Pulse By Pulse Over Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 25V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Latch Up Mode
- Soft Start

### Description

The Fairchild Power Switch(FPS) product family is specially designed for an off line SMPS with minimal external components. The Fairchild Power Switch(FPS) consists of a high voltage power SenseFET and the current mode PWM controller IC. The PWM controller includes an integrated fixed oscillator, the under voltage lock out, the leading edge blanking block, the optimized gate turn-on/turn-off driver, the thermal shut down protection, the over voltage protection, the temperature compensated precision current sources for loop compensation and an fault protection circuit. Compared to just PWM controller combined MosFET or RCC switching converter solution, a Fairchild Power Switch(FPS) can reduce total component price, design size, and weight,also simultaneously increase efficiency, productivity, and system reliability. It has a simple method of application well suited for cost down design in either a flyback converter or a forward converter.



### Internal Block Diagram



Rev.1.0.1

## Absolute Maximum Ratings

| Parameter                                            | Symbol       | Value            | Unit                |
|------------------------------------------------------|--------------|------------------|---------------------|
| Drain-Gate Voltage ( $R_{GS}=1M\Omega$ )             | $V_{DGR}$    | 800              | V                   |
| Gate-Source (GND) Voltage                            | $V_{GS}$     | $\pm 30$         | V                   |
| Drain Current Pulsed <sup>(2)</sup>                  | $I_{DM}$     | 32.0             | ADC                 |
| Single Pulsed Avalanche Energy <sup>(3)</sup>        | EAS          | 810              | mJ                  |
| Avalanche Current <sup>(4)</sup>                     | $I_{AS}$     | 15               | A                   |
| Continuous Drain Current ( $T_C=25^\circ\text{C}$ )  | $I_D$        | 8.0              | ADC                 |
| Continuous Drain Current ( $T_C=100^\circ\text{C}$ ) | $I_D$        | 5.6              | ADC                 |
| Maximum Supply Voltage                               | $V_{CC,MAX}$ | 30               | V                   |
| Input Voltage Range                                  | $V_{FB}$     | -0.3 to $V_{SD}$ | V                   |
| Total Power Dissipation                              | $P_D$        | 190              | W                   |
|                                                      | Derating     | 1.54             | W/ $^\circ\text{C}$ |
| Operating Ambient Temperature                        | $T_A$        | -25 to +85       | $^\circ\text{C}$    |
| Storage Temperature                                  | $T_{STG}$    | -55 to +150      | $^\circ\text{C}$    |

**Note:**

1.  $T_j = 25^\circ\text{C}$  to  $150^\circ\text{C}$
2. Repetitive rating: Pulse width limited by maximum junction temperature
3.  $L = 24\text{mH}$ ,  $V_{DD} = 50\text{V}$ ,  $R_G = 25\Omega$ , starting  $T_j = 25^\circ\text{C}$
4.  $L = 13\mu\text{H}$ , starting  $T_j = 25^\circ\text{C}$

## Electrical Characteristics (SFET part)

(Ta=25°C unless otherwise specified)

| Parameter                                            | Symbol              | Condition                                                                                                                                                                  | Min. | Typ. | Max. | Unit |
|------------------------------------------------------|---------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| Drain-Source Breakdown Voltage                       | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V, I <sub>D</sub> =50μA                                                                                                                                  | 800  | -    | -    | V    |
| Zero Gate Voltage Drain Current                      | I <sub>DSS</sub>    | V <sub>DS</sub> =Max., Rating,<br>V <sub>GS</sub> =0V                                                                                                                      | -    | -    | 50   | μA   |
|                                                      |                     | V <sub>DS</sub> =0.8Max., Rating,<br>V <sub>GS</sub> =0V, T <sub>C</sub> =125°C                                                                                            | -    | -    | 200  | μA   |
| Static Drain-Source On Resistance <sup>(note1)</sup> | R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V, I <sub>D</sub> =5.0A                                                                                                                                 | -    | 1.2  | 1.5  | Ω    |
| Forward Transconductance <sup>(note1)</sup>          | g <sub>fs</sub>     | V <sub>DS</sub> =15V, I <sub>D</sub> =5.0A                                                                                                                                 | 1.5  | 2.5  | -    | S    |
| Input Capacitance                                    | C <sub>iss</sub>    | V <sub>GS</sub> =0V, V <sub>DS</sub> =25V,<br>f=1MHz                                                                                                                       | -    | 2460 | -    | pF   |
| Output Capacitance                                   | C <sub>oss</sub>    |                                                                                                                                                                            | -    | 210  | -    |      |
| Reverse Transfer Capacitance                         | C <sub>rss</sub>    |                                                                                                                                                                            | -    | 64   | -    |      |
| Turn On Delay Time                                   | t <sub>d(on)</sub>  | V <sub>DD</sub> =0.5BV <sub>DSS</sub> , I <sub>D</sub> =8.0A<br>(MOSFET switching<br>time are essentially<br>independent of<br>operating temperature)                      | -    | -    | 90   | nS   |
| Rise Time                                            | t <sub>r</sub>      |                                                                                                                                                                            | -    | 95   | 200  |      |
| Turn Off Delay Time                                  | t <sub>d(off)</sub> |                                                                                                                                                                            | -    | 150  | 450  |      |
| Fall Time                                            | t <sub>f</sub>      |                                                                                                                                                                            | -    | 60   | 150  |      |
| Total Gate Charge<br>(Gate-Source+Gate-Drain)        | Q <sub>g</sub>      | V <sub>GS</sub> =10V, I <sub>D</sub> =8.0A,<br>V <sub>DS</sub> =0.5BV <sub>DSS</sub> (MOSFET<br>switching time are<br>essentially independent of<br>operating temperature) | -    | -    | 150  | nC   |
| Gate-Source Charge                                   | Q <sub>gs</sub>     |                                                                                                                                                                            | -    | 20   | -    |      |
| Gate-Drain (Miller) Charge                           | Q <sub>gd</sub>     |                                                                                                                                                                            | -    | 70   | -    |      |

### Note:

1. Pulse test: Pulse width ≤ 300μS, duty cycle ≤ 2%

2.  $S = \frac{1}{R}$

**Electrical Characteristics (CONTROL part)** (Continued)

(Ta=25°C unless otherwise specified)

| Parameter                                                     | Symbol               | Condition                                                | Min. | Typ. | Max. | Unit  |
|---------------------------------------------------------------|----------------------|----------------------------------------------------------|------|------|------|-------|
| <b>UVLO SECTION</b>                                           |                      |                                                          |      |      |      |       |
| Start Threshold Voltage                                       | V <sub>START</sub>   | -                                                        | 14   | 15   | 16   | V     |
| Stop Threshold Voltage                                        | V <sub>STOP</sub>    | After turn on                                            | 8    | 9    | 10   | V     |
| <b>OSCILLATOR SECTION</b>                                     |                      |                                                          |      |      |      |       |
| Initial Frequency                                             | F <sub>OSC</sub>     | -                                                        | 60   | 66   | 72   | kHz   |
| Frequency Change With Temperature <sup>(2)</sup>              | $\Delta F/\Delta T$  | -25°C ≤ Ta ≤ +85°C                                       | -    | ±5   | ±10  | %     |
| Maximum Duty Cycle                                            | D <sub>max</sub>     | -                                                        | 45   | 50   | 55   | %     |
| <b>FEEDBACK SECTION</b>                                       |                      |                                                          |      |      |      |       |
| Feedback Source Current                                       | I <sub>FB</sub>      | Ta=25°C, 0V ≤ V <sub>fb</sub> ≤ 3V                       | 0.7  | 0.9  | 1.1  | mA    |
| Shutdown Delay Current                                        | I <sub>delay</sub>   | Ta=25°C, 5V ≤ V <sub>fb</sub> ≤ V <sub>SD</sub>          | 4.0  | 5.0  | 6.0  | μA    |
| <b>SOFT START SECTION</b>                                     |                      |                                                          |      |      |      |       |
| Soft Start Voltage                                            | V <sub>SS</sub>      | V <sub>FB</sub> = 2V                                     | 4.7  | 5.0  | 5.3  | V     |
| Soft Start Current                                            | I <sub>SS</sub>      | Sync & S/S=GND                                           | 0.8  | 1.0  | 1.2  | mA    |
| <b>REFERENCE SECTION</b>                                      |                      |                                                          |      |      |      |       |
| Output Voltage <sup>(1)</sup>                                 | V <sub>ref</sub>     | Ta=25°C                                                  | 4.80 | 5.00 | 5.20 | V     |
| Temperature Stability <sup>(1)(2)</sup>                       | V <sub>ref</sub> /ΔT | -25°C ≤ Ta ≤ +85°C                                       | -    | 0.3  | 0.6  | mV/°C |
| <b>CURRENT LIMIT (SELT-PROTECTION)SECTION</b>                 |                      |                                                          |      |      |      |       |
| Peak Current Limit                                            | I <sub>OVER</sub>    | Max. inductor current                                    | 4.40 | 5.00 | 5.60 | A     |
| <b>PROTECTION SECTION</b>                                     |                      |                                                          |      |      |      |       |
| Thermal Shutdown Temperature (T <sub>j</sub> ) <sup>(1)</sup> | T <sub>SD</sub>      | -                                                        | 140  |      |      | °C    |
| Over Voltage Protection Voltage                               | V <sub>OV</sub> P    | -                                                        | 25   | 28   | 31   | V     |
| Over Current Protection Voltage                               | V <sub>OC</sub> P    | -                                                        | 1.05 | 1.10 | 1.15 | V     |
| <b>TOTAL DEVICE SECTION</b>                                   |                      |                                                          |      |      |      |       |
| Start Up Current                                              | I <sub>START</sub>   | V <sub>CC</sub> =14V                                     | -    | 40   | 80   | μA    |
| Operating Supply Current<br>(Control Part Only)               | I <sub>OP</sub>      | Ta=25°C                                                  | -    | 8    | 12   | mA    |
|                                                               | I <sub>op(lat)</sub> | After latch,<br>V <sub>cc</sub> =V <sub>stop</sub> -0.1V | 150  | 250  | 350  | μA    |
| Shutdown Feedback Voltage                                     | V <sub>SD</sub>      | -                                                        | 6.9  | 7.5  | 8.1  | V     |

**Note:**

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process



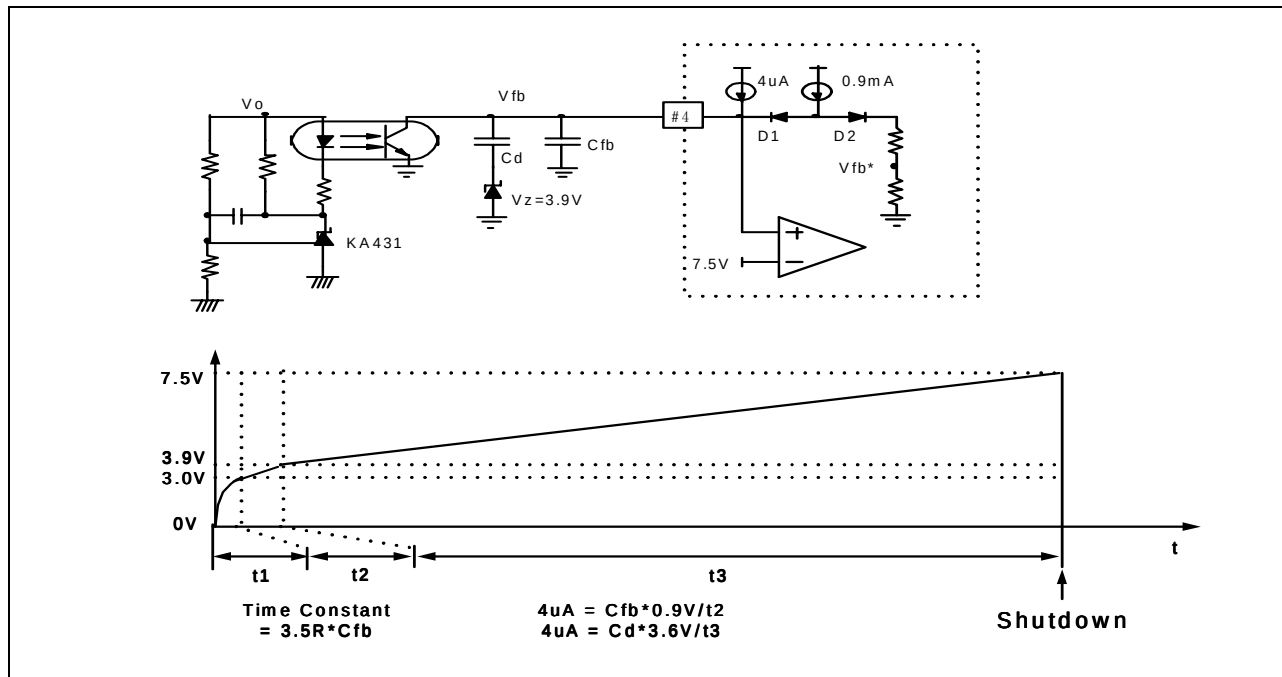


Figure 3. SPS Delayed Shutdown

circuit can perform undesired operations even during transient state, which lasts until normal operation. As a measure against this problem, this protection circuit in the SPS operates after a specified period to determine whether the condition is a transient or an overload. This is done to prevent protection circuit operation during a transient state, which returns normal after a specified period. This operation is described as follows.

Because the FPS uses the current control mode, it cannot flow current over the set maximum current, and therefore the maximum input power is restricted at the characteristic voltage. Therefore, if the output consumes beyond this maximum power,  $V_O$ , shown in the figure below, becomes less than the set voltage and only the provided minimum current can flow through KA431. As a result, the secondary current of the photocoupler becomes almost zero. If all the SPS's 0.9mA current source flows through the internal resistor ( $2.5R + R \approx 3k$ ),  $V_{fb}$  becomes approximately 3V, and the 4uA current starts to charge  $C_{fb}$ . Because the photocoupler secondary current is almost zero,  $V_{fb}$  continues to increase until it reaches 7.5V, at which time the SPS shutsdown. The delay time to shutdown is the time required to charge  $C_{fb}$  to 4.5V with 4uA and can be easily set. When  $C_{fb}$  is 10nF(103),  $t_2$  is approximately 11.2ms and when 0.1uF(104) approximately 120ms. With this amount of the SPS does not shutdown for most transient states. Just increasing  $C_{fb}$  to obtain a longer delay time can become a problem, because  $C_{fb}$  is an important parameter for determining the response speed (Dynamic Response) of the SMPS. Similarly,  $V_{fb}$  exceeds 3V and the 4uA current starts to charge the  $C_{fb}$ . At this time,  $V_{fb}$  continues to increase until it becomes 7.5V, at which time a resistor could be added between the F/B pin and GND to lengthen the time to

SPS shutdown. If a part of delay current go through the added resistor, the time to shutdown can be lengthened. In our test the delay shutdown time with  $C_{fb}$ (473) and resistor (3.9M) is about two times longer than with only  $C_{fb}$ (473). When  $V_{fb}$  is 7.5V, the current flowing through this 3.9M resistor is approximately 1.9uA. To obtain the same results, if a zener diode (about 3.9 ~ 4.7V) in series connection with a capacitor is parallel-connected to  $C_{fb}$ , as depicted in Fig 3., the desired shutdown delay time could be obtained according to the size of the capacitor.

#### Over voltage Protection Circuit

The FPS has a self-protection feature against malfunctions, such as feedback circuit open or short-circuit. When the feedback terminal short circuits as seen from the primary side, the feedback terminal voltage becomes zero, and switching cannot start as a result. If the feedback terminal opens, then the protection circuit initiates as in the overload protection circuit. If the feedback terminal looks open due to a malfunction in the secondary side feedback circuit or a non-solder, the primary side continues to switch with the set maximum current until the protection circuit come on; therefore, it is normal for the secondary side voltage to become much greater than the rated voltage. If there was no protection circuit guarding against such conditions, the fuse can blow or, even more serious, a fire can start. Even if it does not lead such dire circumstances, the IC connected to the secondary side without a regulator could be destroyed (especially the digital IC such as TTL IC etc.) For such instances, time, the over voltage protection circuit (protection against feedback circuit abnormalities) starts to operate in the SPS. In such circumstances, the output voltage, which increases tremendously, is made proportional

to the SPS  $V_{CC}$  voltage. If  $V_{CC}$  exceeds 24 V, the SPS IC starts the protection circuit. Therefore,  $V_{CC}$  should be appropriately kept below 24V during normal operation.

### OCP (Over Current Protection)

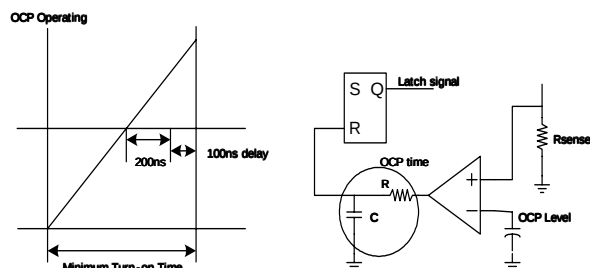


Figure 5. OCP Function & Block

The FPS has various built-in, basic protection features. They are the UVLO (Under Voltage Lock Out), OLP (Over Load Protection) and OCP (Over Current Protection). However, if a secondary side diode short or load short occur due to a worst case condition, such as a maximum input voltage

putting a large strain on the device, another external component may need to be added. By adding these requirements in the FPS, superior reliability and advantageous cost can be achieved. When gate on signal of the SenseFet is received, simultaneously the OCP block senses  $I_{peak}$  through the sense resistor for 1 $\mu$ s. After the OCP block has turned on, the voltage across the resistor is compared to the pre-set voltage in the comparator, and, if it takes longer than 200ns within the allowed comparison time of 1 $\mu$ s, then the comparator produces a high signal, which latches the OCP. fig 4. shows the OCP latch waveform. When there is a diode short/load short, the SPS turns on for the minimum turn-on time. If the instantaneous current is of the form shown in fig 4., the OCP block opens a 1 $\mu$ s window to compare the voltage proportional to the current across the resistor with the reference voltage and latches. Here, the 100ns delay after the 200ns is the delay time to SenseFET gate off and is generated from the comparison of the voltage across the sense resistor.

### Soft start operation

Normally, the SMPS output voltage increases from start up with a fixed time constant. This is due to the capacitive component of the load. At start up, therefore, the feedback signal applied to the PWM comparator's inverting input reaches its maximum value (1V). This is because the feedback loop is effectively open. Also at this time, the drain current is at its peak value ( $I_{peak}$ ) and maximum allowable power is being delivered to the secondary load. With that said, note that when the SMPS pushes maximum power to the secondary side for this initial fixed time, the

entire

circuit is seriously stressed. Use of a soft start function avoids such stresses. Figure 6 shows how to implement a soft start for a Fairchild Power Switch(FPS). At turn on, the soft start capacitor on pin 5 of the Fairchild Power Switch(FPS) starts to charge through the 1mA current source. When the voltage across  $C_S$  reaches 3V, diode  $D_S$  turns off. No more current flows to it from the 1mA current source.  $C_S$  then continues to charge to 5V through the 20k $\Omega$  resistor.

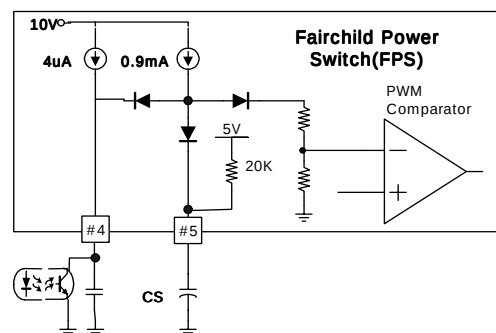
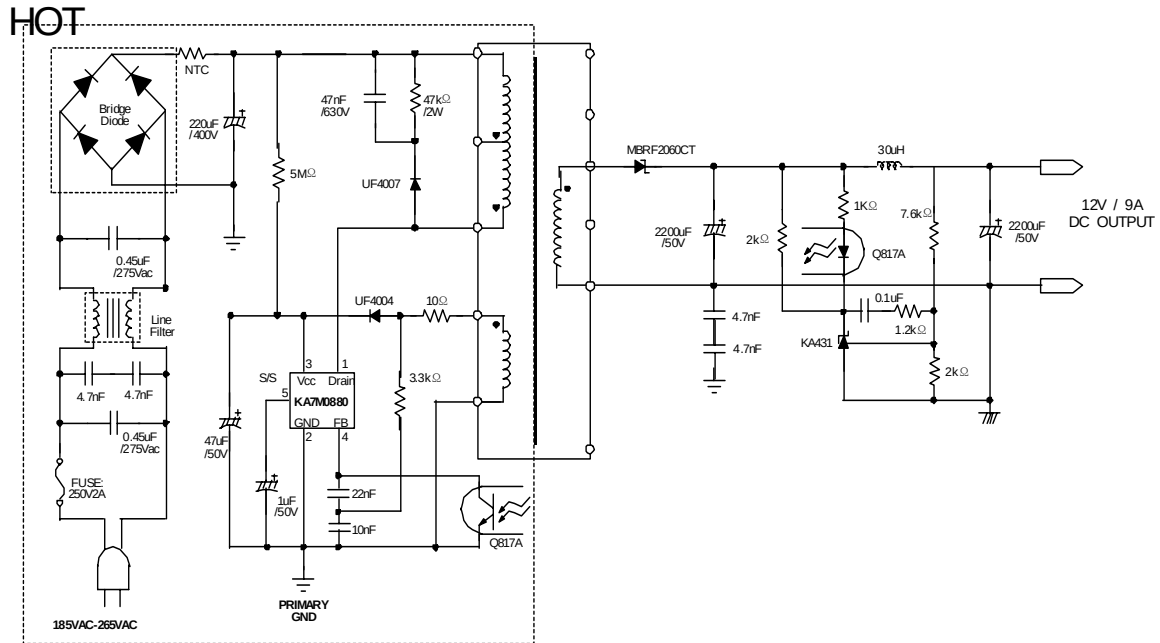


Figure 6. Soft Start Circuit.

Note that when the voltage across  $C_S$  exceeds 3V, The voltage at the comparator's inverting terminal no longer follows the voltage across  $C_S$ . Instead, it follows the output voltage feedback signal. In shutdown or protection circuit operation, capacitor  $C_S$  is discharged, to enable it to charge from 0V at restart.

### 3. Application Note using the SPS

#### -Flyback Application (100W)



### Transformer Specification

#### 2. Winding Specification

| No.                                                   | PIN(S → F) | WIRE                | TURNS | WINDING METHOD   |
|-------------------------------------------------------|------------|---------------------|-------|------------------|
| NP/2                                                  | 1 → 3      | 0.4 $\phi \times 1$ | 42    | SOLENOID WINDING |
| INSULATION : POLYESTER TAPE t = 0.050mm, 1Layer       |            |                     |       |                  |
| N+12V                                                 | 12 → 13    | 14mm $\times$ 1     | 8     | COPPER WINDING   |
| INSULATION : POLYESTER TAPE t = 0.050mm, 3Layer       |            |                     |       |                  |
| NB                                                    | 8 → 7      | 0.3 $\phi \times 1$ | 9     | SOLENOID WINDING |
| INSULATION : POLYESTER TAPE t = 0.050mm, 1Layer       |            |                     |       |                  |
| NP/2                                                  | 3 → 4      | 0.4 $\phi \times 1$ | 42    | SOLENOID WINDING |
| OUTER INSULATION : POLYESTER TAPE t = 0.050mm, 3Layer |            |                     |       |                  |

#### 3. Electrical Characteristic

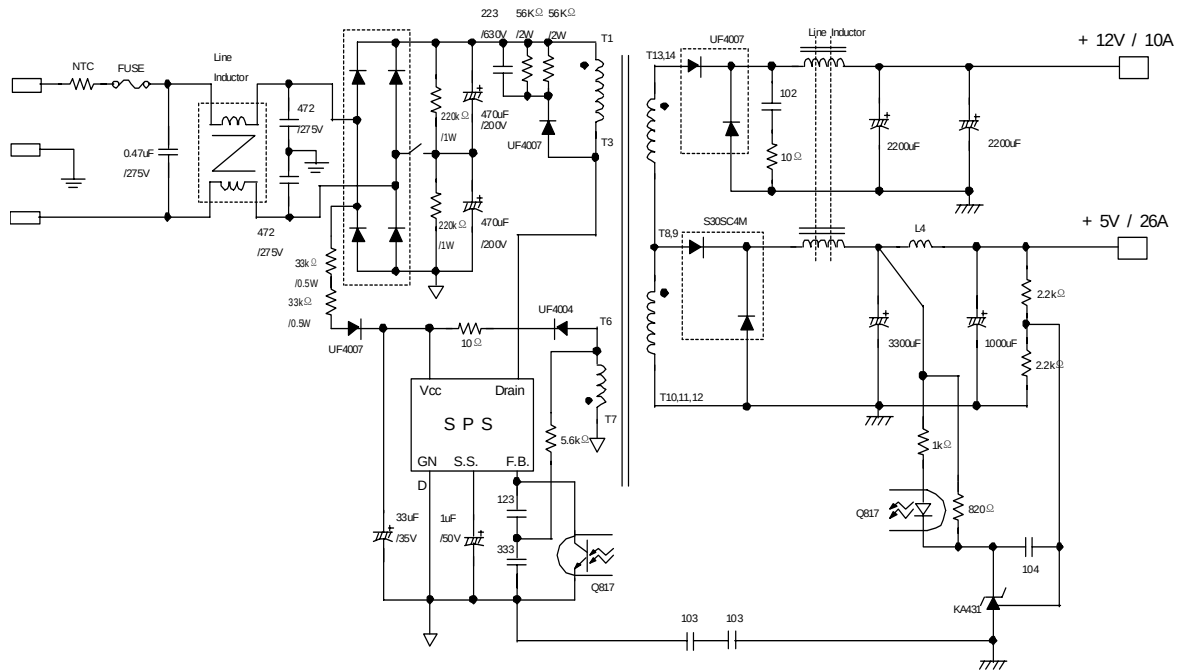
| CLOSURE    | PIN   | SPEC.           | REMARKS       |
|------------|-------|-----------------|---------------|
| INDUCTANCE | 1 - 4 | 700uH $\pm$ 10% | 1kHz, 1V      |
| LEAKAGE L  | 1 - 4 | 10uH MAX.       | 2nd ALL SHORT |

#### 4. Core & Bobbin

CORE : EER 4042

BOBBIN : EER4042

## -Forward Application (250W)



## Transformer Specification

### 2. Winding Specification

| No.   | PIN(S → F)        | WIRE            | TURNS | WINDING METHOD   |
|-------|-------------------|-----------------|-------|------------------|
| Np/2  | 1 → 3             | 0.65 $\phi$ × 1 | 50T   | SOLENOID WINDING |
| N+5V  | 8, 9 → 10, 11, 12 | 14mm × 1        | 4T    | COPPER WINDING   |
| N+12V | 13, 14 → 9        | 0.65 $\phi$ × 4 | 5T    | SOLENOID WINDING |
| Np/2  | 1 → 3             | 0.65 $\phi$ × 1 | 50T   | SOLENOID WINDING |
| NVCC  | 7 → 6             | 0.65 $\phi$ × 1 | 6T    | SOLENOID WINDING |

### 3. Electrical Characteristic

| CLOSURE    | PIN   |
|------------|-------|
| INDUCTANCE | 1 - 3 |
| LEAKAGE L  | 1 - 3 |

### 4. Secondary Inductor(L2) Specification

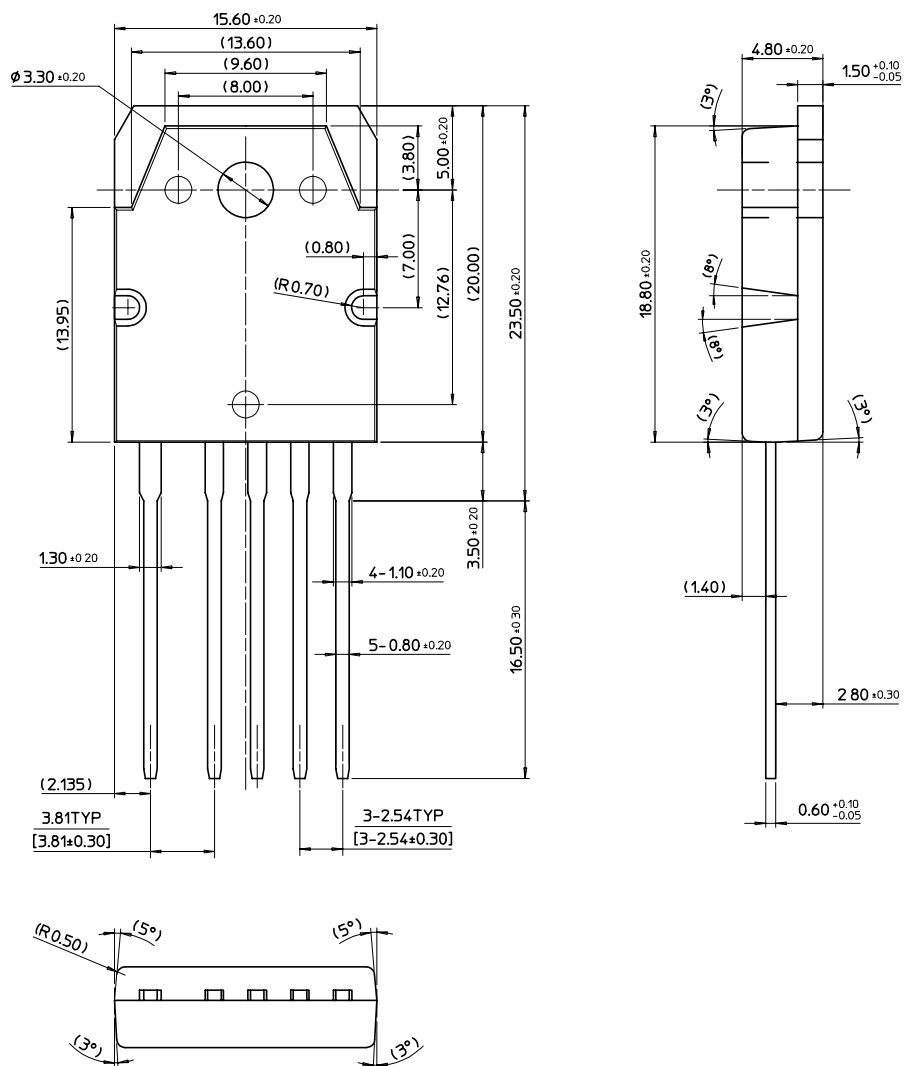
Core : Power Core 27  $\phi$  16 Grade

5V : 12T (1  $\phi$  × 2)

10V : 27T (1.2  $\phi$  × 1)

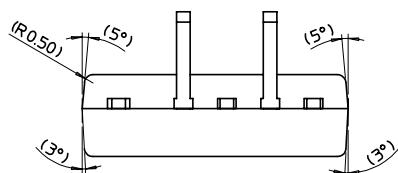
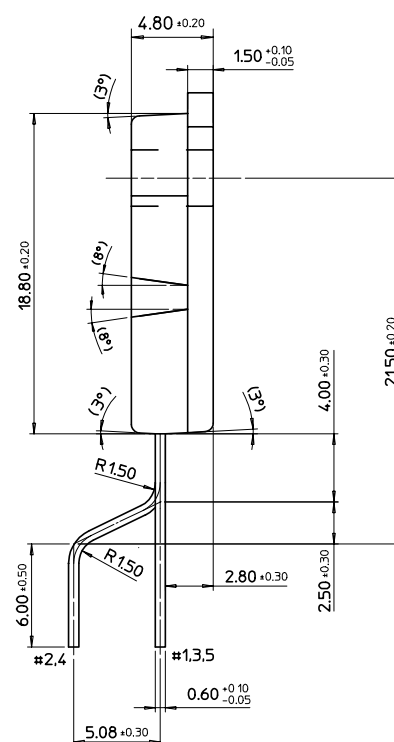
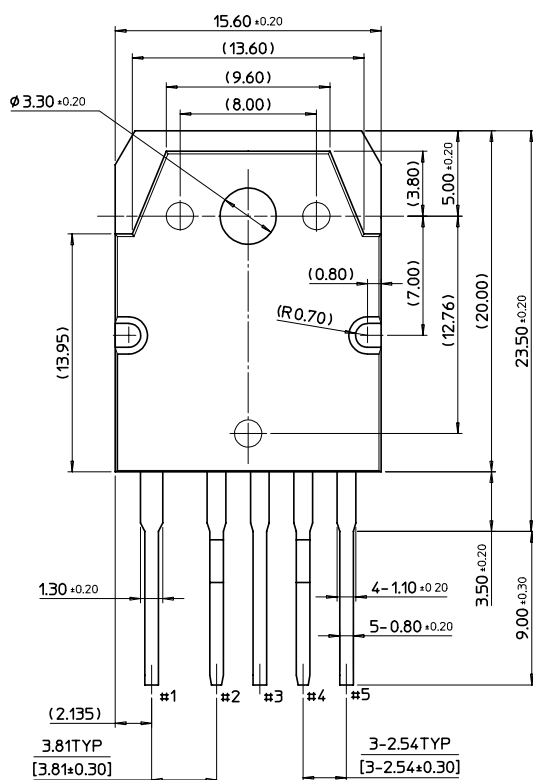
## Package Dimensions

## TO-3P-5L



# Package Dimensions (Continued)

## TO-3P-5L(Forming)



## Ordering Information

| Product Number | Package           | Rating   | Fosc  |
|----------------|-------------------|----------|-------|
| FS7M0880TU     | TO-3P-5L          | 800V, 8A | 67kHz |
| FS7M0880YDTU   | TO-3P-5L(Forming) |          |       |

TU : Non Forming Type

YDTU : Forming type

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